

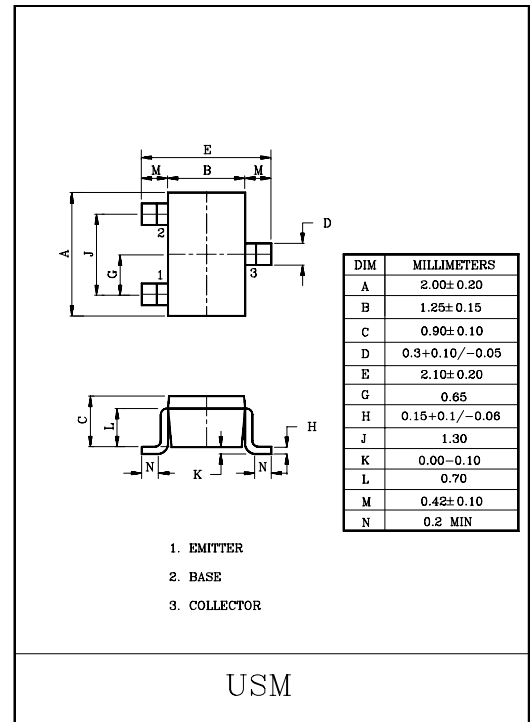
HIGH SPEED SWITCHING APPLICATION.

FEATURES

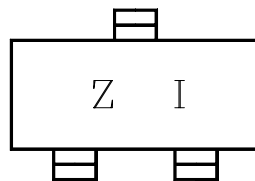
- High Frequency Characteristics
: $f_T=500\text{MHz}$ (Min.) ($V_{CE}=10\text{V}$, $f=100\text{MHz}$, $I_C=10\text{mA}$).
- Excellent Switching Characteristics.

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

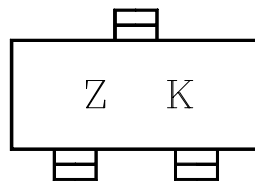
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	40	V
Collector-Emitter Voltage	V_{CEO}	15	V
Emitter-Base Voltage	V_{EBO}	4.5	V
Collector Current	I_C	500	mA
Collector Power Dissipation ($T_a=25^\circ\text{C}$)	P_C	100	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-55 \sim 150$	$^\circ\text{C}$



Marking



KTN2369V



KTN2369AV

MARK SPEC

TYPE	MARK
KTN2369U	Z I
KTN2369AU	Z K

KTN2369U/AU

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I _{CBO}	V _{CB} =20V, I _E =0	–	–	0.4	μA
			V _{CB} =20V, I _E =0, Ta=125°C	–	–	30	
Collector-Base Breakdown Voltage		V _{(BR)CBO}	I _C =10μA, I _E =0	40	–	–	V
Collector-Emitter Breakdown Voltage *		V _{(BR)CEO}	I _E =10mA, I _B =0	15	–	–	
Emitter-Base Breakdown Voltage		V _{(BR)EBO}	I _E =10μA, I _C =0	4.5	–	–	
DC Current Gain *	KTN2369U	h _{FE}	I _C =10mA, V _{CE} =1.0V	40	–	120	
	KTN2369AU			–	–	120	
	KTN2369U		I _C =10mA, V _{CE} =1.0V, Ta=-55°C	20	–	–	
	KTN2369AU		I _C =10mA, V _{CE} =0.35V, Ta=-55°C	20	–	–	
	KTN2369U		I _C =100mA, V _{CE} =2.0V	20	–	–	
	KTN2369AU		I _C =100mA, V _{CE} =1.0V	20	–	–	
Collector-Emitter Saturation Voltage *		V _{CE(sat)}	I _C =10mA, I _B =1.0mA	–	–	0.25	V
Base-Emitter Saturation Voltage *		V _{BE(sat)}	I _C =10mA, I _B =1.0mA	0.70	–	0.85	V
Transition Frequency		f _T	I _C =10mA, V _{CE} =10V, f=100MHz	500	–	–	MHz
Collector Output Capacitance		C _{ob}	V _{CB} =5.0V, I _E =0, f=1.0MHz	–	–	4.0	pF
Storage Time	KTN2369AU	T _{stg}	I _C =100mA, I _{B1} =-I _{B2} =10mA, V _{CC} =10V	–	–	13	nS
Turn-on Time		t _{on}	V _{CC} =3.0V, I _C =10mA, I _{B1} =3.0mA, I _{B2} =-1.5mA	–	–	12	
Turn-off Time	KTN2369AU	t _{off}	I _C =10mA, I _{B1} =3.0mA, I _{B2} =-1.5mA, V _{CC} =3.0V	–	–	15	

Note : *Pulse Test : Pulse Width ≤300μS, Duty Cycle≤2.0%